TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

HN1K04FU

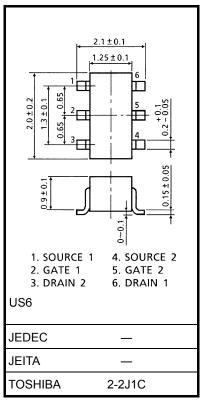
High Speed Switching Applications Analog Switch Applications

Unit: mm

- High input impedance and extremely low drive current.
- V_{th} is low and it is possible to drive directly at low-voltage CMOS. : V_{th} = 0.8 to 2.5 V
- Switching speed is fast.
- Suitable for high-density mounting because of a compact package.

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DS}	50	V
Gate-source voltage	V _{GSS}	10	٧
DC drain current	ID	50	mA
Drain power dissipation	P _D (Note 1)	200	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C



Weight: 6.8 mg

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

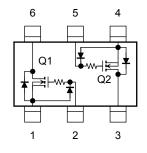
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: TOTAL rating

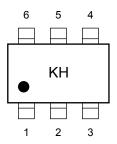
Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = 10 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	1	μА
Drain-source breakdown voltage	V (BR) DSS	$I_D = 100 \ \mu A, \ V_{GS} = 0 \ V$	50	_	_	V
Drain cut-off current	I _{DSS}	V _{DS} = 50V, V _{GS} = 0 V	_	_	1	μΑ
Gate threshold voltage	V _{th}	$V_{DS} = 5V$, $I_{D} = 0.1$ mA	0.8	_	2.5	V
Forward transfer admittance	Y _{fs}	$V_{DS} = 5V, I_D = 10 \text{ mA}$	20	_	_	mS
Drain-source ON resistance	R _{DS} (ON)	$I_D = 10 \text{ mA}, V_{GS} = 4.0 \text{ V}$	_	20	50	Ω
Input capacitance	C _{iss}	V _{DS} = 5 V, V _{GS} =0 V, f = 1 MHz	_	6.3	_	pF
Reverse transfer capacitance	C _{rss}	V _{DS} = 5 V, V _{GS} =0 V, f = 1 MHz	_	1.3	_	pF
Output capacitance	Coss	V _{DS} = 5 V, V _{GS} =0 V, f = 1 MHz	_	5.7	_	pF
Switching time	t _{on}	$V_{DD} = 5 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0 \text{ to } 4.0 \text{ V}$	_	0.11	_	0
	t _{off}	$V_{DD} = 5 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0 \text{ to } 4.0 \text{ V}$	_	0.15	_	μS

Equivalent Circuit (top view)



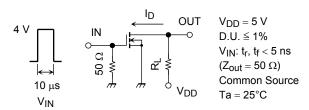
Marking



(Q1, Q2 common)

Switching Time Test Circuit

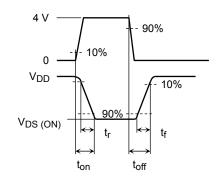
(a) Test circuit



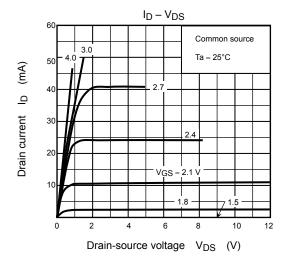
(b) V_{IN}

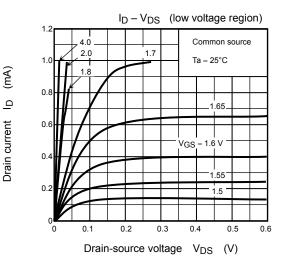
 V_{GS}

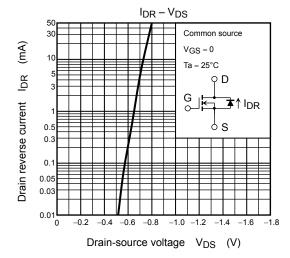
(c) V_{OUT} V_{DS}

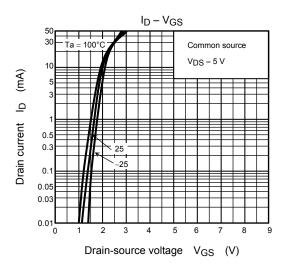


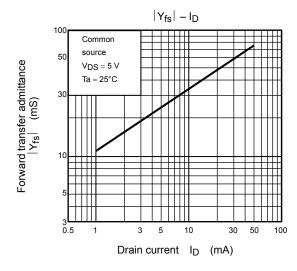
(Q1, Q2 common)

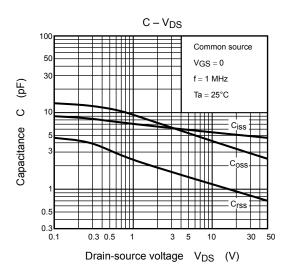




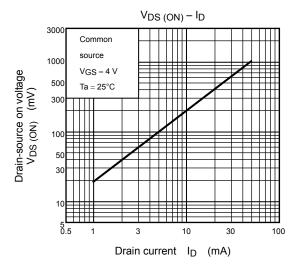


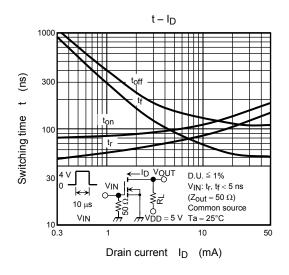


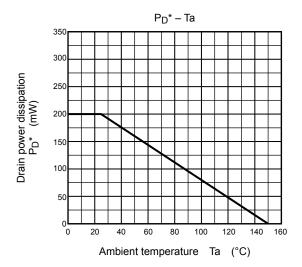




(Q1, Q2 common)







*: TOTAL rating

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20070701-EN GENERAL

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